### SHENZHEN HAOLIN ELECTRONICS TECHNOLOGY CO., LTD



# **TO-92 Plastic-Encapsulate Transistors**

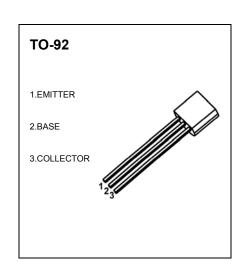
**A92** TRANSISTOR (PNP)

#### **FEATURES**

High voltage

### MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	-310	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-305	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
Ic	Collector Current -Continuous	-200	mA	
I <sub>CM</sub>	Collector Current -Pulsed	-500	mA	
Pc	Collector Power Dissipation	625	mW	
T <sub>j</sub>	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55-150	$^{\circ}$	
R <sub>OJA</sub>	Thermal Resistance, Junction to Ambient	200	°C/mW	
R <sub>eJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/mW	



#### **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-100uA, I <sub>E</sub> =0	-310			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-1mA, I <sub>B</sub> =0	-305			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I <sub>E</sub> =-100μA, I <sub>C</sub> =0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -200 V I <sub>E</sub> =0			-0.25	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5 V, I <sub>C</sub> =0			-0.1	μΑ
	h <sub>FE(1)</sub>	V <sub>CE</sub> = -10 V, IC=- 1 mA	60			
DC current gain	h <sub>FE(2)</sub>	$V_{CE}$ = -10V, $I_{C}$ = -10 mA	80		250	
	h <sub>FE(3)</sub>	$V_{CE}$ = -10 V, $I_{C}$ = -80 mA	60			
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = -20 mA, IB= -2 mA			-0.2	V
Base-emitter saturation voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = -20 mA, IB= -2 mA			-0.9	V
Transition frequency	f⊤	V <sub>CE</sub> = -20 V, IC= -10 mA f = 30MHz	50			MHz

### CLASSIFICATION OF h<sub>FE(2)</sub>

Rank	А	B <sub>1</sub>	B <sub>2</sub>	С
Range	80-100	100-150	150-200	200-250

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